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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/748,389	12/29/2003	Mineo Yamakawa	21058/0206773-US0	8159
75172 Client 21058	7590 12/19/200	8	EXAM	IINER
c/o DARBY & DARBY P.C. P.O. BOX 770 CHURCH STREET STATION NEW YORK, NY 10008-0770			WRIGHT, PATRICIA KATHRYN	
			ART UNIT	PAPER NUMBER
			1797	
			MAIL DATE	DELIVERY MODE
			12/19/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Advisory Action Before the Filing of an Appeal Brief

Application No.	Applicant(s)		
10/748,389	YAMAKAWA ET AL.		
Examiner	Art Unit		

	P. Kathryn Wright	1797	
The MAILING DATE of this communication appe	ars on the cover sheet with the	correspondence address	
THE REPLY FILED 09 December 2008 FAILS TO PLACE THIS	APPLICATION IN CONDITION F	FOR ALLOWANCE.	
1. The reply was filed after a final rejection, but prior to or on application, applicant must timely file one of the following r application in condition for allowance; (2) a Notice of Appe for Continued Examination (RCE) in compliance with 37 C periods:	the same day as filing a Notice of eplies: (1) an amendment, affidav al (with appeal fee) in compliance	Appeal. To avoid abandonment of this it, or other evidence, which places the with 37 CFR 41.31; or (3) a Request	
a) The period for reply expires <u>3</u> months from the mailing date	of the final rejection.		
b) The period for reply expires on: (1) the mailing date of this Adno event, however, will the statutory period for reply expire la Examiner Note: If box 1 is checked, check either box (a) or (the MONTHS OF THE FINAL REJECTION. See MPEP 706.07(f.)	ter than SIX MONTHS from the mailin b). ONLY CHECK BOX (b) WHEN THE).	g date of the final rejection. E FIRST REPLY WAS FILED WITHIN TWC	
Extensions of time may be obtained under 37 CFR 1.136(a). The date of have been filed is the date for purposes of determining the period of extender 37 CFR 1.17(a) is calculated from: (1) the expiration date of the slaset forth in (b) above, if checked. Any reply received by the Office later may reduce any earned patent term adjustment. See 37 CFR 1.704(b). NOTICE OF APPEAL	ension and the corresponding amount nortened statutory period for reply orig	of the fee. The appropriate extension fee inally set in the final Office action; or (2) as	
 The Notice of Appeal was filed on A brief in compl filing the Notice of Appeal (37 CFR 41.37(a)), or any exten Notice of Appeal has been filed, any reply must be filed with AMENDMENTS 	sion thereof (37 CFR 41.37(e)), to	avoid dismissal of the appeal. Since a	Э
			
 The proposed amendment(s) filed after a final rejection, be They raise new issues that would require further con They raise the issue of new matter (see NOTE below 	sideration and/or search (see NO v);	TE below);	
(c) They are not deemed to place the application in bett	er form for appeal by materially re	ducing or simplifying the issues for	
appeal; and/or (d) ☐ They present additional claims without canceling a c	orresponding number of finally rei	ected claims	
NOTE: (See 37 CFR 1.116 and 41.33(a)).	orresponding number of finding reg	edica ciaims.	
4. The amendments are not in compliance with 37 CFR 1.12	1. See attached Notice of Non-Co	empliant Amendment (PTOL-324).	
5. Applicant's reply has overcome the following rejection(s):		(
 Newly proposed or amended claim(s) would be allowed non-allowable claim(s). 	owable if submitted in a separate,		
7. For purposes of appeal, the proposed amendment(s): a) [how the new or amended claims would be rejected is prov The status of the claim(s) is (or will be) as follows:		ll be entered and an explanation of	
Claim(s) allowed:			
Claim(s) objected to: Claim(s) rejected: <u>1,10-22,31-40,56,57,61,62 and 64-66</u> .			
Claim(s) withdrawn from consideration:			
<u>AFFIDAVIT OR OTHER EVIDENCE</u> 8.	before or on the date of filing a N	ation of Annual will not be entared	
because applicant failed to provide a showing of good and was not earlier presented. See 37 CFR 1.116(e).			
9. The affidavit or other evidence filed after the date of filing a entered because the affidavit or other evidence failed to over showing a good and sufficient reasons why it is necessary	vercome <u>all</u> rejections under appe	al and/or appellant fails to provide a	
10. ☐ The affidavit or other evidence is entered. An explanation REQUEST FOR RECONSIDERATION/OTHER	of the status of the claims after e	ntry is below or attached.	
11. The request for reconsideration has been considered but See Continuation Sheet.	does NOT place the application in	n condition for allowance because:	
12. ☐ Note the attached Information <i>Disclosure Statement</i>(s). (l13. ☐ Other:	PTO/SB/08) Paper No(s)		
/Jill Warden/ Supervisory Patent Examiner, Art Unit 1797			

Continuation of 11. does NOT place the application in condition for allowance because: of arguments of record. Further, Applicant do not agree with the Examiner that it would have been obvious to modify the coated porous polycarbonate membrane (PCTE) of Bohn with an uncoated porous silicon membrane because the factual basis for the Examiner to arrive at this conclusion stems from hindsight gained from Applicants' own invention.

The Examiner respectfully disagrees. First, the claims are not limited to an uncoated porous silicon membrane. Secondly, Applicant's cite a portion of the rejection in which the Examienr noted that, like Bohn, Applicant teaches the addition of a sensor layer as an alterative to use of a base silicon substrate. Contrary to Applicant's assertion, this was not used to by the Office to provide the reason why it would have been obvious to substitute the membrane of Bohn with the Zimmmermann. This was noted by the Examiner to contridict Applicant's previous assertion that the polycarbonate film in Bohn's device is not capable of exhibiting sensing characteristics causing a change in at least one of an optical and electrical characteristic in response to exposure to a targeted fluid or reaction because the polycarbonate in Bohn includes a semiconductor material (i.e., gold) that can be used for electronics and photovoltaic applications. Thus, both the present invention and the Bohn reference teach a membrane with an additional sensor layer. The stated reason for substituting the Bohn polycarbonate membrane with that of Zimmermann is set forth at page 6, 2nd full paragraph (i.e., Zimmermann teaches the equivalence of a porous silicon membrane and a porous polycarbonate membrane). Therefore, the Examiner uses the teaching in Zimmermann, not Applicant's disclosure, to reach the obviousness determination.

Applicant also argues that the silicon nitride of Zimmermann neither contains nor is equivalent to "a porous silicon membrane." Applicant's state that "porous silicon" is a term of art and has been defined as "a form of the chemical element silicon which has an introduced nanoporous holes in its microstructure ". First, the porous membrane is specifically defined in Applicant's specification as made of silicon, polydimethyl siloxane, or single crystal porous silicon having a pore size between 50 angstroms and 10 microns (See claims 50 and 60 for example). Thus, the teaching of the prior art is moot since the membrane is defined in the specification. Lastly, Zimmermann does teach a porous silicon nitride membrane having diameter ranging from 0.01 micron to 8 microns, see paragraph [0027], within Applicant's pore diameter range.

Applicant argues that porous silicon and porous silicon nitride are not the same. Applicant merely asserts silicon nitride does necessarily contain elemental silicon. Clearly this is not correct based on chemical formula of silicon nitride (Si3N4), which shows elemental silicon Si. Also note that Applicant teaches the porous membrane is made of a porous polydimethyl siloxane (PDMS). Thus, the silicon membrane in claim 1 need not be purely silicon.

Applicant merely asserts the silicon nitride is not capable performing a sensing characteristics causing a change in at least one of an optical and electrical characteristic in response to exposure to a targeted fluid or reaction because silicon nitride is insulating.

The Examiner disagrees with Applicant argument. Applicant is reminded that one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See In re Keller, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); In re Merck & Co., 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). The Examiner does not rely on Zimmermann for the teaching of silicon nitride performing a sensing characteristics causing a change in at least one of an optical and electrical characteristic in response to exposure to a targeted fluid or reaction because silicon nitride is insulating, rather the combination of Bohn and Zimmermann as set forth in the rejection. Furthermore unoxidized porous silicon can be insulating (see col. 2, lines 7-14 in US Patent No. 5,936, 257 to Kusunoki et al.) and abstract of US pub. No. 2006/0255425 to Xie.

Thus, for the reasons set forth above, the claims remain rejected over the prior art.

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